

2 μA Low-Dropout Positive Voltage Regulator

Features

- 2.0 µA Typical Quiescent Current
- · Input Operating Voltage Range up to 10.0V
- · Low-Dropout Voltage (LDO):
 - 120 mV (typical) @ 100 mA
 - 380 mV (typical) @ 200 mA
- High Output Current: 250 mA (V_{OUT} = 5.0V)
- High-Accuracy Output Voltage: ±2% (max)
- Low Temperature Drift: ±100 ppm/°C (typical)
- Excellent Line Regulation: 0.2%/V (typical)
- Package Options: 3-Pin SOT-23A, 3-Pin SOT-89, and 3-Pin TO-92
- · Short Circuit Protection
- · Standard Output Voltage Options:
 - 1.8V, 2.5V, 3.0V, 3.3V, 5.0V

Applications

- · Battery-Powered Devices
- · Battery-Powered Alarm Circuits
- · Smoke Detectors
- CO² Detectors
- · Smart Battery Packs
- PDAs
- · Low-Quiescent Current Voltage Reference
- · Cameras and Portable Video Equipment
- · Pagers and Cellular Phones
- · Solar-Powered Instruments
- · Consumer Products
- · Microcontroller Power

General Description

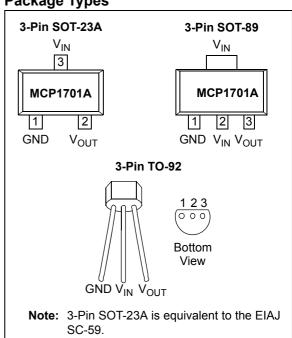
The MCP1701A is a family of CMOS low-dropout, positive voltage regulators that can deliver up to 250 mA of current while consuming only 2.0 µA of quiescent current (typ.). The input operating range is specified up to 10V, making it ideal for lithium-ion (one or two cells), 9V alkaline and other two and three primary cell battery-powered applications.

The MCP1701A is capable of delivering 250 mA with an input-to-output voltage differential (dropout voltage) of 650 mV. The low-dropout voltage extends the battery operating lifetime. It also permits high currents in small packages when operated with minimum V_{IN} - V_{OUT} differentials. The MCP1701A offers improved startup and transient response.

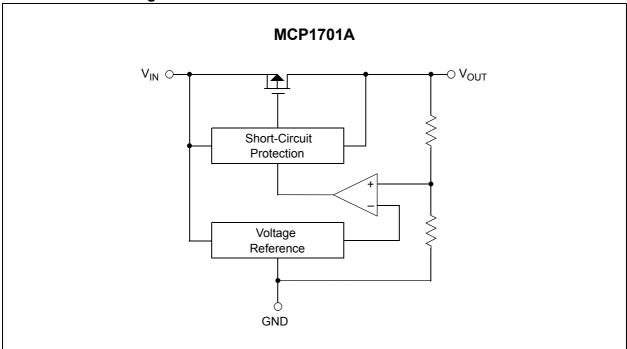
The MCP1701A has a tight tolerance output voltage regulation of ±0.5% (typ.) and very good line regulation at ±0.2%. The LDO output is stable when using only 1 μF of output capacitance of either tantalum or aluminum-electrolytic style capacitors. The MCP1701A LDO also incorporates short circuit protection to ensure maximum reliability.

Package options include the 3-pin SOT-23A, 3-pin SOT-89 and 3-Pin TO-92.

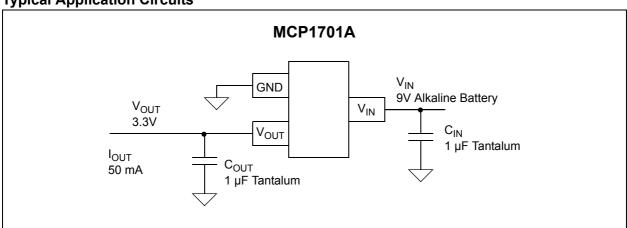
Package Types



Functional Block Diagram



Typical Application Circuits



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Input Voltage	+12V
Output Current (Continu	ious)P _D /(V _{IN} – V _{OUT})mA
Output Current (peak)	500 mA
Output Voltage	(GND – 0.3V) to (V _{IN} + 0.3V)
Continuous Power Diss	ipation:
3-Pin SOT-23A	150 mW
3-Pin SOT-89	500 mW
3-Pin TO-92	300 mW

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

Electrical Specifications: Unless otherwise specified, all limits are established for an ambient temperature of T _A = +25°C.								
Parameters	Sym	Min	Тур	Max	Units	Conditions		
Output Voltage Regulation	V _{OUT}	V _R - 2%	V _R ±0.5%	V _R + 2%	V	I _{OUT} = 40 mA (Note 1)		
Maximum Output Current	I _{OUTMAX}	250	_	_	mA	$V_{OUT} = 5.0V$ $(V_{IN} = V_R + 1.0V)$		
		200	_	_		V _{OUT} = 4.0V		
		150	_	_		V _{OUT} = 3.3V		
		150	_	_		V _{OUT} = 3.0V		
		125		_		V _{OUT} = 2.5V		
		110	_	_		V _{OUT} = 1.8V		
Load Regulation (Note 3)	$\Delta V_{OUT}/V_{OUT}$	-1.60	±0.8	+1.60	%	V_{OUT} = 5.0V, 1 mA \leq I _{OUT} \leq 100 mA		
		-2.25	±1.1	+2.25		V_{OUT} = 4.0V, 1 mA $\leq I_{OUT} \leq$ 100 mA		
		-2.72	±1.3	+2.72		V_{OUT} = 3.3V, 1 mA $\leq I_{OUT} \leq$ 80 mA		
		-3.00	±1.5	+3.00		V_{OUT} = 3.0V, 1 mA $\leq I_{OUT} \leq$ 80 mA		
		-3.60	±1.8	+3.60		V_{OUT} = 2.5V, 1 mA $\leq I_{OUT} \leq$ 60 mA		
		-1.60	±0.8	+1.60		V _{OUT} = 1.8V, 1 mA ≤ I _{OUT} ≤ 30 mA		
Dropout Voltage	V _{IN} - V _{OUT}	_	380	600	mV	I _{OUT} = 200 mA, V _R = 5.0V		
		_	400	630		I _{OUT} = 200 mA, V _R = 4.0V		
		_	400	700		I _{OUT} = 150 mA, V _R = 3.3V		
		_	400	700		I _{OUT} = 150 mA, V _R = 3.0V		
		_	400	700		I _{OUT} = 120 mA, V _R = 2.5V		
		_	180	300		I _{OUT} = 20 mA, V _R = 1.8V		
Input Quiescent Current	IQ	_	2.0	4.5	μΑ	V _{IN} = V _R + 1.0V		
Line Regulation	ΔV _{OUT} •100	_	0.2	0.3	%/V	I_{OUT} = 40 mA, $(V_R + 1) \le V_{IN} \le 10.0V$		
	ΔV _{IN} •V _{OUT}							
Input Voltage	V _{IN}	_	_	10	V			
Temperature Coefficient of Output Voltage	TCV _{OUT}	_	±100	_	ppm/ °C	I_{OUT} = 40 mA, -40°C \leq T _A \leq +85°C (Note 2)		
Output Rise Time	T _R	_	200	_	μs	10% V_R to 90% V_R , V_{IN} = 0V to V_R +1V, R_L = 25 Ω resistive		

- 1: V_R is the nominal regulator output voltage. For example: $V_R = 1.8V$, 2.5V, 3.3V, 4.0V, 5.0V. The input voltage $V_{IN} = V_R + 1.0V$, $I_{OUT} = 40$ mA.
- 2: TCV_{OUT} = (V_{OUT-HIGH} V_{OUT-LOW}) *10⁶ / (V_R * ΔTemperature), V_{OUT-HIGH} = Highest voltage measured over the temperature range. V_{OUT-LOW} = Lowest voltage measured over the temperature range.
- 3: Load regulation is measured at a constant junction temperature using low duty cycle pulse testing.

TEMPERATURE CHARACTERISTICS

Parameters	Sym	Min	Тур	Max	Units	Conditions
Temperature Ranges						
Specified Temperature Range (I)	T _A	-40	_	+85	°C	
Storage Temperature Range	T _A	-40	_	+125	°C	
Package Thermal Resistances	•	•				
Thermal Resistance, 3L-SOT-23A	θ_{JA}	_	335	_	°C/W	Minimum trace width single layer application
			230	_	°C/W	Typical FR4, 4-layer application
Thermal Resistance, 3L-SOT-89	$\theta_{\sf JA}$	_	52	_	°C/W	Typical, when mounted on 1 square inch of copper
Thermal Resistance, 3L-TO-92	$\theta_{\sf JA}$	_	131.9	_	°C/W	EIA/JEDEC JESD51-751-7 4-layer board

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Notes: Unless otherwise specified, V_{OUT} = 1.8V, 3.3V, 5.0V, T_A = +25°C, C_{IN} = 1 μF Tantalum, C_{OUT} = 1 μF Tantalum.

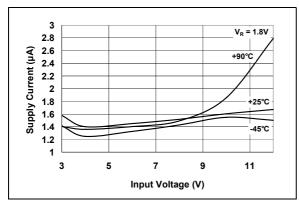


FIGURE 2-1: Supply Current vs. Input Voltage ($V_R = 1.8V$).

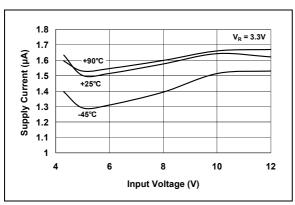


FIGURE 2-2: Supply Current vs. Input Voltage ($V_R = 3.3V$).

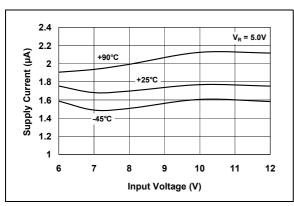


FIGURE 2-3: Supply Current vs. Input Voltage ($V_R = 5.0V$).

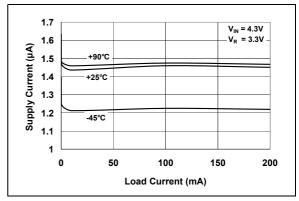


FIGURE 2-4: Supply Current vs. Load Current ($V_R = 3.3V$).

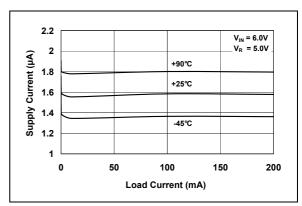


FIGURE 2-5: Supply Current vs. Load Current ($V_R = 5.0V$).

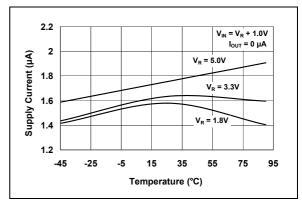


FIGURE 2-6: Supply Current vs. Temperature.

Note: Unless otherwise indicated, V_{OUT} = 1.8V, 3.3V, 5.0V, T_A = +25°C, C_{IN} = 1 μF Tantalum, C_{OUT} = 1 μF Tantalum.

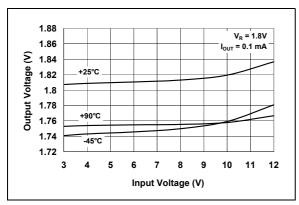


FIGURE 2-7: Output Voltage vs. Input Voltage $(V_R = 1.8V)$.

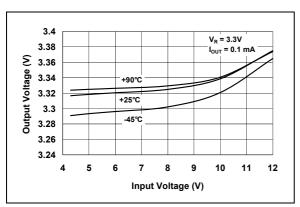


FIGURE 2-8: Output Voltage vs. Input Voltage $(V_R = 3.3V)$.

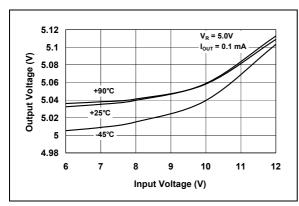


FIGURE 2-9: Output Voltage vs. Input Voltage $(V_R = 5.0V)$.

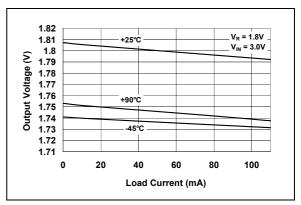


FIGURE 2-10: Output Voltage vs. Load Current ($V_R = 1.8V$).

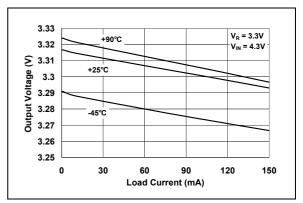


FIGURE 2-11: Output Voltage vs. Load Current ($V_R = 3.3V$).

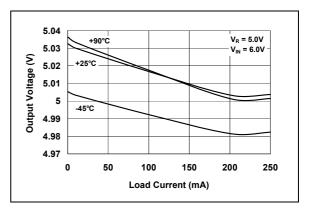


FIGURE 2-12: Output Voltage vs. Load Current ($V_R = 5.0V$).

Note: Unless otherwise indicated, V_{OUT} = 1.8V, 3.3V, 5.0V, T_{A} = +25°C, C_{IN} = 1 μF Tantalum, C_{OUT} = 1 μF Tantalum.

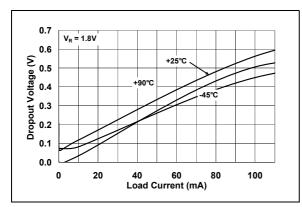


FIGURE 2-13: Dropout Voltage vs. Load Current ($V_R = 1.8V$).

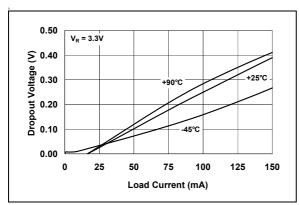


FIGURE 2-14: Dropout Voltage vs. Load Current ($V_R = 3.3V$).

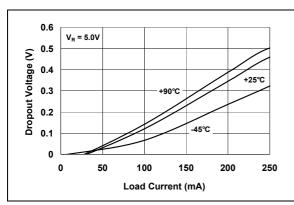


FIGURE 2-15: Dropout Voltage vs. Load Current ($V_R = 5.0V$).

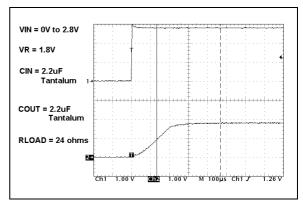


FIGURE 2-16: Start-up From V_{IN} $(V_R = 1.8V)$.

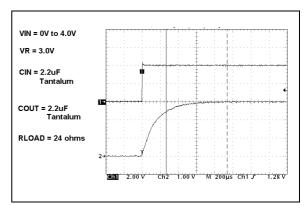


FIGURE 2-17: Start-up From V_{IN} ($V_R = 3.3V$).

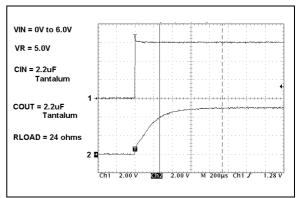


FIGURE 2-18: Start-up From V_{IN} ($V_R = 5.0V$).

Note: Unless otherwise indicated, V_{OUT} = 1.8V, 3.3V, 5.0V, T_A = +25°C, C_{IN} = 1 μF Tantalum, C_{OUT} = 1 μF Tantalum.

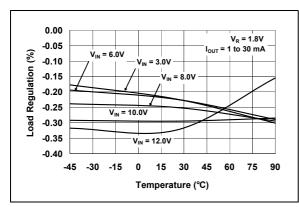


FIGURE 2-19: Load Regulation vs. Temperature ($V_R = 1.8V$).

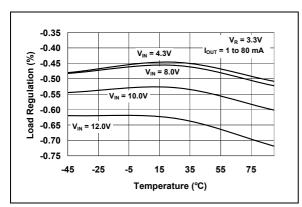


FIGURE 2-20: Load Regulation vs. Temperature ($V_R = 3.3V$).

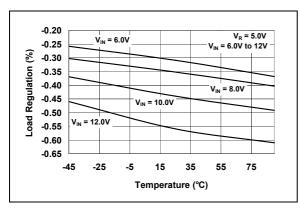


FIGURE 2-21: Load Regulation vs. Temperature ($V_R = 5.0V$).

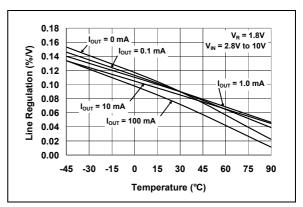


FIGURE 2-22: Line Regulation vs. Temperature ($V_R = 1.8V$).

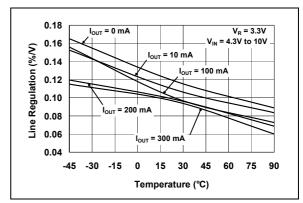


FIGURE 2-23: Line Regulation vs. Temperature ($V_R = 3.3V$).

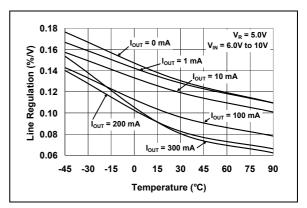


FIGURE 2-24: Line Regulation vs. Temperature ($V_R = 5.0V$).

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

Pin No. SOT-23A	Pin No. SOT-89	Pin No. TO-92	Name Function	
1	1	1	GND	Ground Terminal
2	3	3	V _{OUT}	Regulated Voltage Output
3	2	2	V _{IN}	Unregulated Supply Input

3.1 Ground Terminal (GND)

Regulator ground. Tie GND to the negative side of the output and the negative side of the input capacitor. Only the LDO bias current (2 μ A, typ.) flows out of this pin, there is no high current. The LDO output regulation is referenced to this pin. Minimize voltage drops between this pin and the negative side of the load.

3.2 Regulated Voltage Output (V_{OUT})

Connect V_{OUT} to the positive side of the load and the positive terminal of the output capacitor. The positive side of the output capacitor should be physically located as close as possible to the LDO V_{OUT} pin. The current flowing out of this pin is equal to the DC load current.

3.3 Unregulated Supply Input (V_{IN})

Connect the input supply voltage and the positive side of the input capacitor to V_{IN}. Like all low-dropout linear regulators, low source impedance is necessary for the stable operation of the LDO. The amount of capacitance required to ensure low source impedance will depend on the proximity of the input source capacitors or battery type. The input capacitor should be physically located as close as possible to the V_{IN} pin. For most applications, 1 µF of capacitance will ensure stable operation of the LDO circuit. For applications that have load currents below 100 mA, the input capacitance requirement can be lowered. The type of capacitor used can be ceramic, tantalum or aluminum electrolytic. The low equivalent series resistance characteristics of the ceramic will yield better noise and PSRR performance at high frequency. The current flow into this pin is equal to the DC load current, plus the LDO bias current (2 µA, typical).

4.0 DETAILED DESCRIPTION

The MCP1701A is a low-quiescent current, precision, fixed-output voltage LDO. Unlike bipolar regulators, the MCP1701A supply current does not increase proportionally with load current.

4.1 Output Capacitor

A minimum of 1 µF output capacitor is required. The output capacitor should have an ESR greater than 0.1 Ω and less than 5 Ω , plus a resonant frequency above 1 MHz. Larger output capacitors can be used to improve supply noise rejection and transient response. Care should be taken when increasing C_{OUT} to ensure that the input impedance is not high enough to cause high input impedance oscillation.

4.2 Input Capacitor

A 1 μF input capacitor is recommended for most applications when the input impedance is on the order of 10 Ω . Larger input capacitance may be required for stability when operating from a battery input, or if there is a large distance from the input source to the LDO. When large values of output capacitance are used, the input capacitance should be increased to prevent high source impedance oscillations.

4.3 Overcurrent

The MCP1701 internal circuitry monitors the amount of current flowing through the P-channel pass transistor. In the event of a short circuit or excessive output current, the MCP1701 will act to limit the output current.

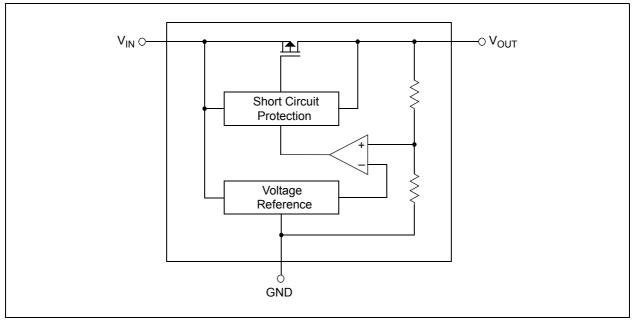


FIGURE 4-1: MCP1701A Block Diagram.

5.0 THERMAL CONSIDERATIONS

5.1 Power Dissipation

The amount of power dissipated internal to the LDO linear regulator is the sum of the power dissipation within the linear pass device (P-channel MOSFET) and the quiescent current required to bias the internal reference and error amplifier. The internal linear pass device power dissipation is calculated as shown in Equation 5-1.

EQUATION 5-1:

$$P_D$$
 (Pass Device) = $(V_{IN} - V_{OUT}) x I_{OUT}$

The internal power dissipation, as a result of the bias current for the LDO internal reference and error amplifier, is calculated as shown in Equation 5-2.

EQUATION 5-2:

$$P_D$$
 (Bias) = $V_{IN} x I_{GND}$

The total internal power dissipation is the sum of P_D (pass device) and P_D (bias).

EQUATION 5-3:

$$P_{TOTAL} = P_D (Pass Device) + P_D (Bias)$$

For the MCP1701A, the internal quiescent bias current is so low (2 μ A, typ.) that the PD (bias) term of the power dissipation equation can be ignored. The maximum power dissipation can be estimated by using the maximum input voltage and the minimum output voltage to obtain a maximum voltage differential between input and output. The next step would be to multiply the maximum voltage differential by the maximum output current.

EQUATION 5-4:

$$P_D = (V_{INMAX} - V_{OUTMIN}) x I_{OUTMAX}$$

Given:

 $V_{IN} = 3.3V \text{ to } 4.1V$ $V_{OUT} = 3.0V \pm 2\%$ $I_{OUT} = 1 \text{ mA to } 100 \text{ mA}$

 $T_{AMAX} = 55^{\circ}C$

 $P_{MAX} = (4.1V - (3.0V \times 0.98)) \times 100 \text{ mA}$

To determine the junction temperature of the device, the thermal resistance from junction-to-ambient must be known. The 3-pin SOT-23A thermal resistance from junction-to-air ($R_{\theta JA}$) is estimated to be approximately 335°C/W. The SOT-89 $R_{\theta JA}$ is estimated to be approximately 52°C/W when mounted on 1 square inch of copper. The $R_{\theta JA}$ will vary with physical layout, airflow and other application-specific conditions.

The device junction temperature is determined by calculating the junction temperature rise above ambient, then adding the rise to the ambient temperature.

EQUATION 5-5: JUNCTION TEMPERATURE – SOT-23A EXAMPLE:

$$\begin{split} T_J &= P_{DMAX} \times R_{\theta JA} + T_A \\ T_J &= 116.0 \text{ milliwatts} \times 335 \text{°C/W} + 55 \text{°C} \\ T_I &= 93.9 \text{°C} \end{split}$$

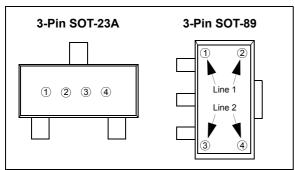
EQUATION 5-6: JUNCTION TEMPERATURE - SOT-89 EXAMPLE:

$$T_J = 116.0 \text{ milliwatts} \times 52 \text{°C/W} + 55 \text{°C}$$

 $T_I = 61 \text{°C}$

6.0 PACKAGING INFORMATION

6.1 Package Marking Information

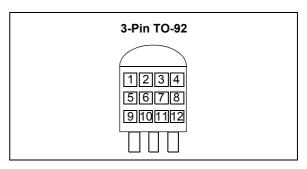


① represents first voltage digit 1V, 2V, 3V, 4V, 5V, 6V

② represents first decimal place voltage (x.0 - x.9)

Symbol	Voltage	Symbol	Voltage
Α	x.0	F	x.5
В	x.1	Н	x.6
С	x.2	K	x.7
D	x.3	L	x.8
Е	x.4	М	x.9

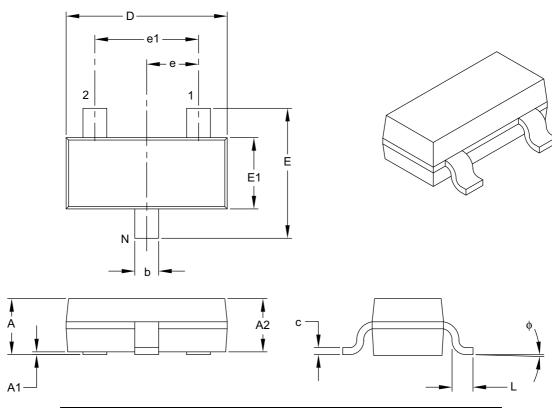
- 3 represents polarity 0 = Positive (fixed)
- ④ represents assembly lot number



- ①, ②, ③ & ④ = 701A (fixed)
- ⑤ represents first voltage digit (1-6)
- 6 represents first voltage decimal (0-9)
- 7 represents extra feature code: fixed: 0
- ® represents regulation accuracy 2 = ±2.0% (standard)
- (9), (10), (11) & (12) represents assembly lot number

3-Lead Plastic Small Outline Transistor (CB) [SOT-23A]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS					
Dimensi	on Limits	MIN	NOM	MAX		
Number of Pins	N	3				
Lead Pitch	е		0.95 BSC			
Outside Lead Pitch	e1		1.90 BSC			
Overall Height	Α	0.89 – 1.45				
Molded Package Thickness	A2	0.90	1.30			
Standoff	A1	0.00	_	0.15		
Overall Width	Е	2.10 – 3.0				
Molded Package Width	E1	1.20 – 1.80				
Overall Length	D	2.70	_	3.10		
Foot Length	L	0.15	-	0.60		
Foot Angle	ф	0°	_	30°		
Lead Thickness	С	0.09 – 0.26				
Lead Width	b	0.30	_	0.51		

Notes:

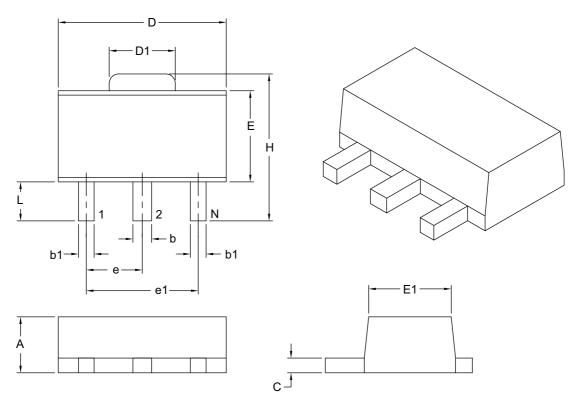
- 1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127 mm per side.
- 2. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-130B

3-Lead Plastic Small Outline Transistor Header (MB) [SOT-89]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIM	ETERS		
Dimension	Dimension Limits			
Number of Leads	N	3		
Pitch	е	1.50	BSC	
Outside Lead Pitch	e1	3.00	BSC	
Overall Height	Α	1.40	1.60	
Overall Width	Н	3.94	4.25	
Molded Package Width at Base	Е	2.29	2.60	
Molded Package Width at Top	E1	2.13	2.29	
Overall Length	D	4.39	4.60	
Tab Length	D1	1.40	1.83	
Foot Length	L	0.79	1.20	
Lead Thickness	С	0.35	0.44	
Lead 2 Width	b	0.41	0.56	
Leads 1 & 3 Width	b1	0.36	0.48	

Notes:

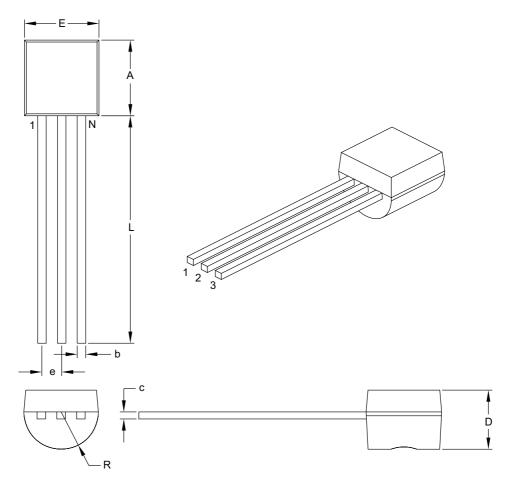
- 1. Dimensions D and E do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.127 mm per side.
- 2. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-029B

3-Lead Plastic Transistor Outline (TO) [TO-92]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	INC	HES	
Dime	nsion Limits	MIN	MAX	
Number of Pins	N	3		
Pitch	е	.050 BSC		
Bottom to Package Flat	D	.125 .165		
Overall Width	E	.175	.205	
Overall Length	А	.170 .210		
Molded Package Radius	R	.080	.105	
Tip to Seating Plane	L	.500	_	
Lead Thickness	С	.014	.021	
Lead Width	b	.014	.022	

Notes:

- 1. Dimensions A and E do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" per side.
- 2. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-101B

NOTES:

APPENDIX A: REVISION HISTORY

Revisions C (February 2007)

• Updated Packaging Information

Revision B (September 2006)

- Numerous changes to Section 1.0. Electrical Characteristics
- Added disclaimer to package outline drawings.

Revision A (February 2006)

• Original Release of this Document.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO. X-	<u>xx</u>	<u>X</u>	<u>X</u>	<u>X</u>	<u>/XX</u>		Exa	mples:	
 Device Tape and Reel	Output Voltage		 Tolerance	l	Package		a)	MCP1701AT-1802I/CB:	1.8V LDO Positive Voltage Regulator, SOT-23A-3 pkg.
Device:	MCP1701A	: 2 µA Low	-Dropout Pos	sitive Volta	age Regulato	r	b)	MCP1701AT-1802I/MB:	1.8V LDO Positive Voltage Regulator, SOT89-3 pkg.
Tape and Reel:	Т = Тар	e and Ree	I				c)	MCP1701A-1802I/TO:	1.8V LDO Positive Voltage Regulator, TO-92 pkg.
Output Voltage:	25 = 2.5\ 30 = 3.0\	V "Standar V "Standar V "Standar	d" d"				d)	MCP1701AT-2502I/CB:	2.5V LDO Positive Voltage Regulator, SOT-23A-3 pkg.
	50 = 5.0	V "Standar V "Standar ctory for ot		ltage opti	ons.		e)	MCP1701A-2502I/TO:	2.5V LDO Positive Voltage Regulator, TO-92 pkg.
Extra Feature Code:	0 = Fixe	ed					f)	MCP1701AT-3002I/CB:	3.0V LDO Positive Voltage Regulator, SOT-23A-3 pkg.
Tolerance:		% (Standar	,				g)	MCP1701AT-3002I/MB:	
Package Type:	CB = 3-P	in SOT-23	A (equivalent	to EIAJ S	SC-59)		h)	MCP1701A-3002I/TO:	· -
	MB = 3-P TO = 3-P	in SOT-89 in TO-92					i)	MCP1701AT-3302I/CB:	3.3V LDO Positive Voltage Regulator, SOT-23A-3 pkg.
							j)	MCP1701AT-3302I/MB:	3.3V LDO Positive Voltage Regulator, SOT89-3 pkg.
							k)	MCP1701AT-5002I/CB:	
							l)	MCP1701AT-5002I/MB:	. •
							m)	MCP1701A-5002I/TO:	5.0V LDO Positive Voltage Regulator, TO-92 pkg.

NOTES:

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